# Single Supply Dual Operational Amplifiers

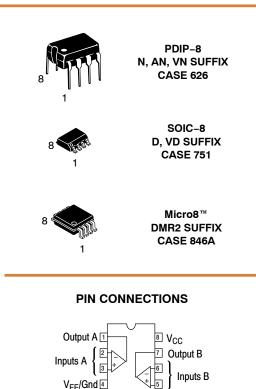
## LM258, LM358, LM358A, LM358E, LM2904, LM2904A, LM2904E, LM2904V, NCV2904

Utilizing the circuit designs perfected for Quad Operational Amplifiers, these dual operational amplifiers feature low power drain, a common mode input voltage range extending to ground/ $V_{EE}$ , and single supply or split supply operation. The LM358 series is equivalent to one-half of an LM324.

These amplifiers have several distinct advantages over standard operational amplifier types in single supply applications. They can operate at supply voltages as low as 3.0 V or as high as 32 V, with quiescent currents about one–fifth of those associated with the MC1741 (on a per amplifier basis). The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications. The output voltage range also includes the negative power supply voltage.

#### Features

- Short Circuit Protected Outputs
- True Differential Input Stage
- Single Supply Operation: 3.0 V to 32 V
- Low Input Bias Currents
- Internally Compensated
- Common Mode Range Extends to Negative Supply
- Single and Split Supply Operation
- ESD Clamps on the Inputs Increase Ruggedness of the Device without Affecting Operation
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



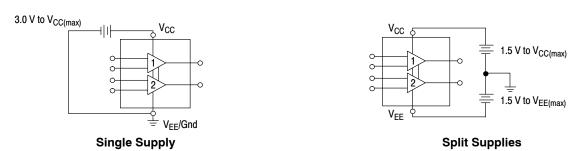
#### **ORDERING INFORMATION**

(Top View)

See detailed ordering and shipping information on page 10 of this data sheet.

#### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 11 of this data sheet.





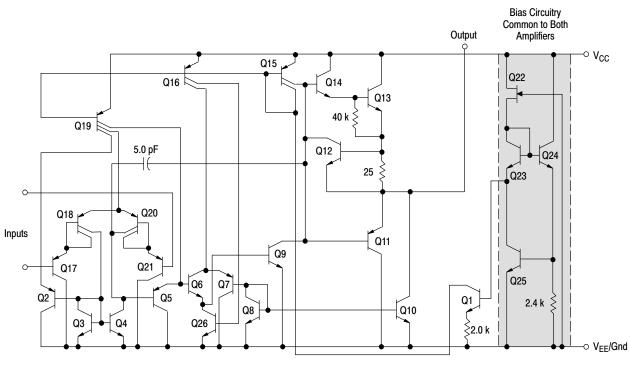


Figure 2. Representative Schematic Diagram (One-Half of Circuit Shown)

#### **MAXIMUM RATINGS** ( $T_A = +25^{\circ}C$ , unless otherwise noted.)

Rating	Symbol	Value	Unit
Power Supply Voltages Single Supply Split Supplies	V <sub>CC</sub> V <sub>CC</sub> , V <sub>EE</sub>	32 ±16	Vdc
Input Differential Voltage Range (Note 1)	V <sub>IDR</sub>	±32	Vdc
Input Common Mode Voltage Range	V <sub>ICR</sub>	-0.3 to 32	Vdc
Output Short Circuit Duration	t <sub>SC</sub>	Continuous	
Junction Temperature	TJ	150	°C
Thermal Resistance, Junction-to-Air (Note 2)   Case 846/     Case 75   Case 62/	007	238 212 161	°C/W
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C
Operating Ambient Temperature Range LM25 LM358, LM358A, LM358I LM2904, LM2904A, LM2904I LM2904V, NCV2904 (Note 3		-25 to +85 0 to +70 -40 to +105 -40 to +125	℃

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Split Power Supplies.

All R<sub>0,JA</sub> measurements made on evaluation board with 1 oz. copper traces of minimum pad size. All device outputs were active.
*NCV2904 is qualified for automotive use.*

#### **ESD RATINGS**

Rating	НВМ	ММ	Unit
ESD Protection at any Pin (Human Body Model – HBM, Machine Model – MM)			
NCV2904 (Note 3)	2000	200	V
LM358E, LM2904E	2000	200	V
LM358DG/DR2G, LM2904DG/DR2G	250	100	V
All Other Devices	2000	200	V

		LM258 LM358, LM358E					858E	I	LM358/	4	
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage $V_{CC}$ = 5.0 V to 30 V, $V_{IC}$ = 0 V to $V_{CC}$ –1.7 V, $V_O \simeq 1.4$ V, $R_S$ = 0 $\Omega$	V <sub>IO</sub>										mV
$T_A = 25^{\circ}C$ $T_A = T_{high}$ (Note 4)		-	2.0 _	5.0 7.0	-	2.0 _	7.0 9.0		2.0 _	3.0 5.0	
$T_A = T_{low}$ (Note 4)		-	-	7.0	-	-	9.0	-	-	5.0	
Average Temperature Coefficient of Input Offset Voltage $T_A = T_{high}$ to $T_{low}$ (Note 4)	$\Delta V_{IO} / \Delta T$	_	7.0	-	-	7.0	-	_	7.0	-	μV/°0
Input Offset Current	I <sub>IO</sub>	_	3.0	30	_	5.0	50	_	5.0	30	nA
$T_A = T_{high}$ to $T_{low}$ (Note 4)	10	-	_	100	-	-	150	-	-	75	
Input Bias Current	I <sub>IB</sub>	-	-45	-150	-	-45	-250	-	-45	-100	
$T_A = T_{high}$ to $T_{low}$ (Note 4)		-	-50	-300	-	-50	-500	-	-50	-200	
Average Temperature Coefficient of Input Offset Current $T_A = T_{high}$ to $T_{low}$ (Note 4)	$\Delta I_{IO} / \Delta T$	-	10	-	-	10	-	-	10	-	pA/°
Input Common Mode Voltage Range (Note 5), $V_{CC} = 30 V$	V <sub>ICR</sub>	0	-	28.3	0	-	28.3	0	-	28.5	V
$V_{CC} = 30$ V, $T_A = T_{high}$ to $T_{low}$		0	-	28	0	-	28	0	-	28	
Differential Input Voltage Range	V <sub>IDR</sub>	-	-	$V_{CC}$	-	-	$V_{CC}$	-	-	$V_{CC}$	V
Large Signal Open Loop Voltage Gain $R_L = 2.0 \text{ k}\Omega, V_{CC} = 15 \text{ V}, \text{ For Large V}_O \text{ Swing},$ $T_A = T_{high} \text{ to } T_{low} \text{ (Note 4)}$	A <sub>VOL</sub>	50 25	100	-	25 15	100	-	25 15	100	-	V/m
Channel Separation 1.0 kHz $\leq f \leq 20$ kHz, Input Referenced	CS	-	-120	_	-	-120	-	_	-120	-	dB
Common Mode Rejection $R_S \leq 10 \ k\Omega$	CMR	70	85	_	65	70	I	65	70	-	dB
Power Supply Rejection	PSR	65	100	-	65	100	-	65	100	-	dB
Output Voltage–High Limit $T_A = T_{high}$ to $T_{low}$ (Note 4) $V_{CC} = 5.0 \text{ V}, \text{ R}_L = 2.0 \text{ k}\Omega, \text{ T}_A = 25^{\circ}\text{C}$	V <sub>OH</sub>	3.3	3.5	_	3.3	3.5	_	3.3	3.5	_	V
$V_{CC} = 30 \text{ V}, \text{ R}_{L} = 2.0 \text{ k}\Omega$		26	-	-	26	-	-	26	-	-	
$V_{CC} = 30 \text{ V}, \text{ R}_{L} = 10 \text{ k}\Omega$		27	28	-	27	28	-	27	28	-	
Output Voltage-Low Limit $V_{CC} = 5.0 \text{ V}, \text{ R}_{L} = 10 \text{ k}\Omega,$ $T_{A} = T_{high} \text{ to } T_{low} \text{ (Note 4)}$	V <sub>OL</sub>	-	5.0	20	-	5.0	20	-	5.0	20	mV
Output Source Current $V_{ID} = +1.0 V$ , $V_{CC} = 15 V$ $T_A = T_{high}$ to $T_{low}$ (LM358A Only)	I <sub>O +</sub>	20	40	-	20	40	-	20 10	40 -	-	mA
Output Sink Current $V_{ID} = -1.0 V, V_{CC} = 15 V$ $T_A = T_{high} \text{ to } T_{low} \text{ (LM358A Only)}$	I <sub>O –</sub>	10	20	-	10	20	-	10 5.0	20	-	mA mA
$V_{\rm ID} = -1.0 \text{ V}, V_{\rm O} = 200 \text{ mV}$		12	50	-	12	50	-	12	50	-	μΑ
Output Short Circuit to Ground (Note 6)	I <sub>SC</sub>	-	40	60	-	40	60	-	40	60	mA
Power Supply Current (Total Device) $T_A = T_{high}$ to $T_{low}$ (Note 4)	I <sub>CC</sub>										mA
		-	1.5 0.7	3.0 1.2	-	1.5 0.7	3.0 1.2	-	1.5 0.7	2.0 1.2	

FI ECTRICAL CHARACTERISTICS	$(V_{CC} = 5.0 \text{ V}, \text{ V}_{FF} = \text{GND}, \text{ T}_{A} = 25^{\circ}\text{C}, \text{ unless otherwise noted.})$
LLLCINICAL CHANACILNISTICS	$V_{CC} = 5.0$ V. $V_{FF} = GIND$ . $I_{\Delta} = 25$ C. UIIIESS UIIEIWISE HOLEU.

4. LM258: T<sub>Iow</sub> = -25°C, T<sub>high</sub> = +85°C LM2904/A/E: T<sub>Iow</sub> = -40°C, T<sub>high</sub> = +105°C NCV2904 is qualified for automotive use.

LM358, LM358A, LM358E:  $T_{low} = 0^{\circ}C$ ,  $T_{high} = +70^{\circ}C$ LM2904V & NCV2904:  $T_{low} = -40^{\circ}C$ ,  $T_{high} = +125^{\circ}C$ 

The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common mode voltage range is V<sub>CC</sub> – 1.7 V.
Short circuits from the output to V<sub>CC</sub> can cause excessive heating and eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.

		LM2	904/LM	2904E	L	_M2904	A	LM29	04V, NC	V2904	
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage V <sub>CC</sub> = 5.0 V to 30 V, V <sub>IC</sub> = 0 V to V <sub>CC</sub> –1.7 V, V <sub>O</sub> $\approx$ 1.4 V, R <sub>S</sub> = 0 $\Omega$	V <sub>IO</sub>										mV
$T_A = 25^{\circ}C$ $T_A = T_{high}$ (Note 7)		-	2.0	7.0 10	-	2.0	7.0 10	-	-	7.0 13	
$T_A = T_{low}$ (Note 7) $T_A = T_{low}$ (Note 7)		_	_	10	-	_	10	_	_	10	
Average Temperature Coefficient of Input Offset Voltage $T_A = T_{high}$ to $T_{low}$ (Note 7)	$\Delta V_{IO} / \Delta T$	-	7.0	-	-	7.0	-	-	7.0	-	μV/°
Input Offset Current	l l a	_	5.0	50	_	5.0	50	_	5.0	50	nA
$T_A = T_{high}$ to $T_{low}$ (Note 7)	lio	_	45	200	_	45	200	_	45	200	
Input Bias Current	I <sub>IB</sub>	_	-45	-250	_	-45	-100	_	-45	-250	
$T_A = T_{high}$ to $T_{low}$ (Note 7)	10	_	-50	-500	-	-50	-250	-	-50	-500	
Average Temperature Coefficient of Input Offset Current	$\Delta I_{\rm IO}/\Delta T$	-	10	-	-	10	_	_	10	-	pA/°
$T_A = T_{high}$ to $T_{low}$ (Note 7)											
Input Common Mode Voltage Range (Note 8), $V_{CC} = 30 \text{ V}$	V <sub>ICR</sub>	0	-	28.3	0	-	28.3	0	-	28.3	V
$V_{CC}$ = 30 V, $T_A$ = $T_{high}$ to $T_{low}$		0	-	28	0	-	28	0	-	28	
Differential Input Voltage Range	V <sub>IDR</sub>	-	-	$V_{CC}$	-	-	V <sub>CC</sub>	-	-	V <sub>CC</sub>	V
Large Signal Open Loop Voltage Gain $R_L = 2.0 \text{ k}\Omega, V_{CC} = 15 \text{ V}, \text{ For Large V}_O \text{ Swing},$ $T_A = T_{high} \text{ to } T_{low} \text{ (Note 7)}$	A <sub>VOL</sub>	25 15	100	-	25 15	100	-	25 15	100	-	V/m
Channel Separation 1.0 kHz $\leq$ f $\leq$ 20 kHz, Input Referenced	CS	-	-120	_	-	-120	-	-	-120	-	dB
Common Mode Rejection $R_S \le 10 \text{ k}\Omega$	CMR	50	70	_	50	70	_	50	70	_	dB
Power Supply Rejection	PSR	50	100	-	50	100	-	50	100	-	dB
Output Voltage–High Limit $T_A = T_{high}$ to $T_{low}$ (Note 7) $V_{CC} = 5.0 \text{ V}, \text{ R}_L = 2.0 \text{ k}\Omega, \text{ T}_A = 25^{\circ}\text{C}$ $V_{CC} = 30 \text{ V}, \text{ R}_L = 2.0 \text{ k}\Omega$	V <sub>OH</sub>	3.3 26	3.5 _		3.3 26	3.5 _	-	3.3 26	3.5 _		V
$V_{CC}$ = 30 V, $R_L$ = 10 k $\Omega$		27	28	-	27	28	-	27	28	-	
Output Voltage–Low Limit $V_{CC}$ = 5.0 V, $R_L$ = 10 k $\Omega$ , $T_A$ = $T_{high}$ to $T_{low}$ (Note 7)	V <sub>OL</sub>	-	5.0	20	-	5.0	20	-	5.0	20	mV
Output Source Current $V_{ID}$ = +1.0 V, $V_{CC}$ = 15 V	I <sub>O+</sub>	20	40	-	20	40	-	20	40	-	mA
Output Sink Current $V_{ID} = -1.0 \text{ V}, V_{CC} = 15 \text{ V}$ $V_{ID} = -1.0 \text{ V}, V_{O} = 200 \text{ mV}$	I <sub>O –</sub>	10	20	-	10 _	20	-	10	20	-	mΑ μΑ
Output Short Circuit to Ground (Note 9)	I <sub>SC</sub>	-	40	60	-	40	60	-	40	60	, mA
Power Supply Current (Total Device) $T_A = T_{high}$ to $T_{low}$ (Note 7)	Icc										mA
$V_{CC} = 30 \text{ V}, V_{O} = 0 \text{ V}, R_{L} = \infty$ $V_{CC} = 5 \text{ V}, V_{O} = 0 \text{ V}, R_{L} = \infty$		-	1.5 0.7	3.0 1.2		1.5 0.7	3.0 1.2	-	1.5 0.7	3.0 1.2	

<b>ELECTRICAL CHARACTERISTICS</b>	(V <sub>CC</sub> = 5.0 V, V <sub>EE</sub> = Gnd, $T_A$ = 25°C, unless otherwise noted.)
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7. LM258: T<sub>Iow</sub> = -25°C, T<sub>high</sub> = +85°C LM2904/A/E: T<sub>Iow</sub> = -40°C, T<sub>high</sub> = +105°C NCV2904 is qualified for automotive use.

LM358, LM358A, LM358E:  $T_{low} = 0^{\circ}C$ ,  $T_{high} = +70^{\circ}C$ LM2904V & NCV2904:  $T_{low} = -40^{\circ}C$ ,  $T_{high} = +125^{\circ}C$ 

8. The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common mode voltage range is  $V_{CC}$  – 1.7 V. 9. Short circuits from the output to  $V_{CC}$  can cause excessive heating and eventual destruction. Destructive dissipation can result from

simultaneous shorts on all amplifiers.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **CIRCUIT DESCRIPTION**

The LM358 series is made using two internally compensated, two-stage operational amplifiers. The first stage of each consists of differential input devices Q20 and Q18 with input buffer transistors Q21 and Q17 and the differential to single ended converter Q3 and Q4. The first stage performs not only the first stage gain function but also performs the level shifting and transconductance reduction functions. By reducing the transconductance, a smaller compensation capacitor (only 5.0 pF) can be employed, thus saving chip area. The transconductance reduction is accomplished by splitting the collectors of Q20 and Q18. Another feature of this input stage is that the input common mode range can include the negative supply or ground, in single supply operation, without saturating either the input devices or the differential to single-ended converter. The second stage consists of a standard current source load amplifier stage.

Each amplifier is biased from an internal-voltage regulator which has a low temperature coefficient thus giving each amplifier good temperature characteristics as well as excellent power supply rejection.

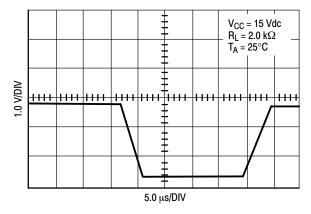
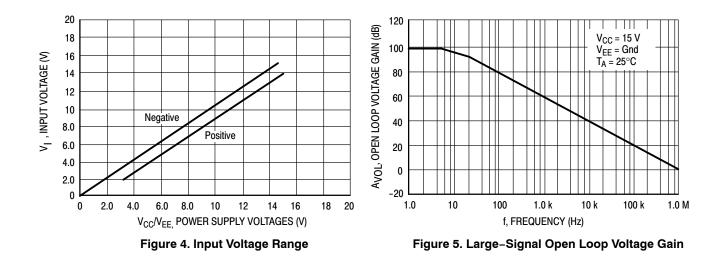


Figure 3. Large Signal Voltage Follower Response



LM258, LM358, LM358A, LM358E, LM2904, LM2904A, LM2904E, LM2904V, NCV2904

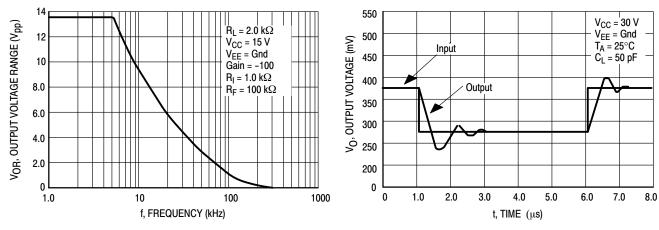
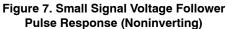
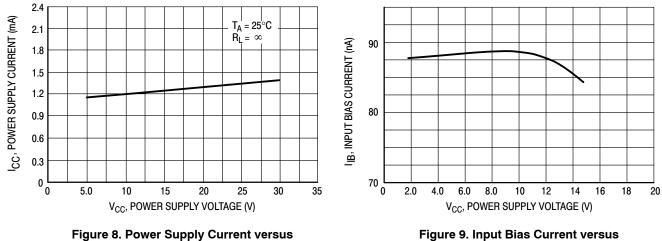


Figure 6. Large–Signal Frequency Response



**Supply Voltage** 



Power Supply Voltage

7

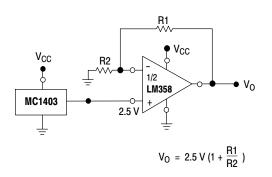


Figure 10. Voltage Reference

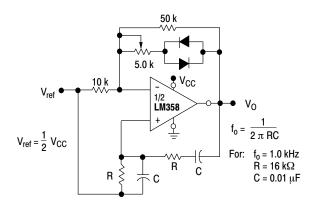


Figure 11. Wien Bridge Oscillator

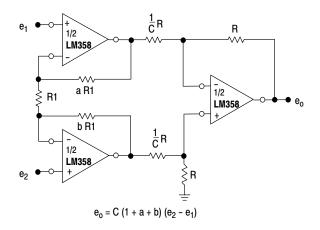
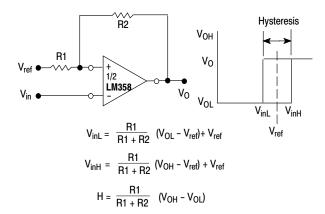


Figure 12. High Impedance Differential Amplifier





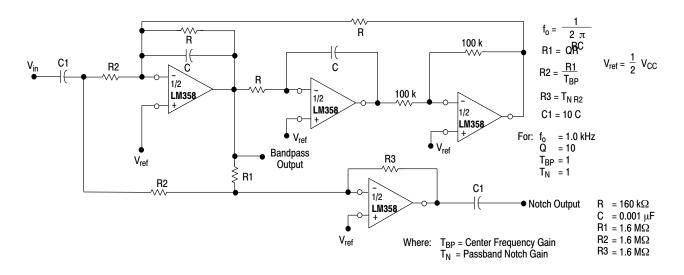
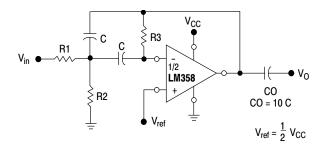


Figure 14. Bi-Quad Filter



Given:  $f_0$  = center frequency A( $f_0$ ) = gain at center frequency

Choose value  $f_0, C$ 

Then: R3 = 
$$\frac{Q}{\pi f_0 C}$$
  
R1 =  $\frac{R3}{2 A(f_0)}$   
R2 =  $\frac{R1 R3}{4Q^2 R1 - R3}$ 

For less than 10% error from operational amplifier.  $\frac{Q_0 f_0}{BW} < 0.1$ 

Where fo and BW are expressed in Hz.

If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 16. Multiple Feedback Bandpass Filter

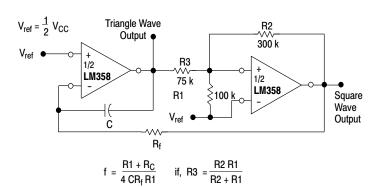


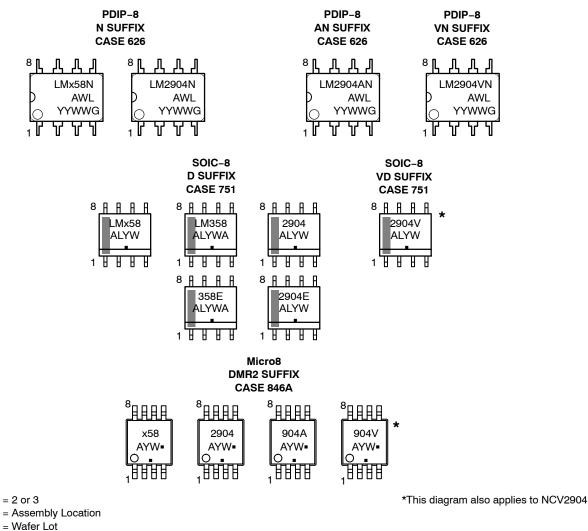
Figure 15. Function Generator

#### ORDERING INFORMATION

Device	Operating Temperature Range	Package	Shipping <sup>†</sup>
LM358ADR2G			2500 / Tape & Reel
LM358DG		SOIC–8 (Pb–Free)	98 Units / Rail
LM358DR2G		(101100)	2500 / Tape & Reel
LM358EDR2G	0°C to +70°C	SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM358DMR2G		Micro8 (Pb–Free)	4000 / Tape & Reel
LM358NG		PDIP-8 (Pb-Free)	50 Units / Rail
LM258DG		SOIC-8	98 Units / Rail
LM258DR2G		(Pb-Free)	2500 / Tape & Reel
LM258DMR2G	−25°C to +85°C	Micro8 (Pb–Free)	4000 / Tape & Reel
LM258NG		PDIP-8 (Pb-Free)	50 Units / Rail
LM2904DG		SOIC-8 (Pb-Free)	98 Units / Rail
LM2904DR2G			2500 / Tape & Reel
LM2904EDR2G		SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM2904DMR2G		Micro8 (Pb–Free)	2500 / Tape & Reel
LM2904NG	-40°C to +105°C	PDIP-8 (Pb-Free)	50 Units / Rail
LM2904ADMG		Micro8	4000 / Tape & Reel
LM2904ADMR2G		(Pb-Free)	4000 / Tape & Reel
LM2904ANG		PDIP-8 (Pb-Free)	50 Units / Rail
LM2904VDG		SOIC-8	98 Units / Rail
LM2904VDR2G		(Pb-Free)	2500 / Tape & Reel
LM2904VDMR2G		Micro8 (Pb–Free)	4000 / Tape & Reel
LM2904VNG	−40°C to +125°C	PDIP-8 (Pb-Free)	50 Units / Rail
NCV2904DR2G*		SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCV2904DMR2G*		Micro8 (Pb–Free)	4000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

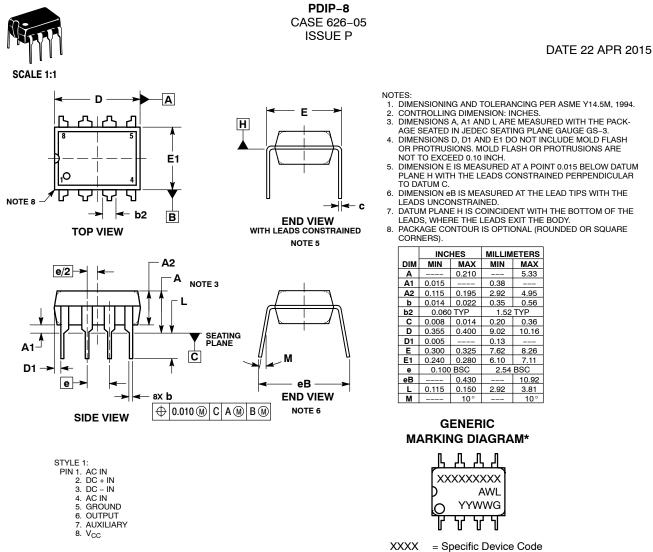


#### **MARKING DIAGRAMS**

- х = 2 or 3
- А
- WL, L
- YY, Y = Year

- WW, W = Work Week
- = Pb-Free Package G
  - = Pb-Free Package (Note: Microdot may be in either location)





A = Assembly Location

- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot " ■", may or may not be present.



# onsemí



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### STYLES ON PAGE 2

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#### SOIC-8 NB CASE 751-07 **ISSUE AK**

STYLE 1: PIN 1. EMITTER COLLECTOR 2. 3. COLLECTOR 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT IOUT 6. IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4 SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5.

6.

7.

8 GATE 1

SOURCE 1/DRAIN 2

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. З. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 MIRROR 1 8. STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT OVI O 2 UVLO З. 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

#### DATE 16 FEB 2011

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 З. BASE #2 COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6 DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW\_TO\_GND 2. DASIC OFF DASIC\_SW\_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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7.

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COLLECTOR, #1

COLLECTOR, #1





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